

UNISONIC TECHNOLOGIES CO., LTD

UTT18P06 Preliminary Power MOSFET

18.3A, 60V P-CHANNEL POWER MOSFET

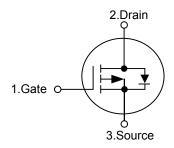
■ DESCRIPTION

The UTC **UTT18P06** is a P-channel power MOSFET using UTC's advanced technology to provide the customers with high switching speed, cost-effectiveness and minimum on-state resistance. It can also withstand high energy in the avalanche.

■ FEATURES

- * $R_{DS(ON)}$ =48 $m\Omega$ V_{GS} =-10V, I_D =-18.3A
- * High Switching Speed

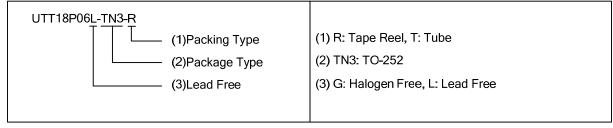


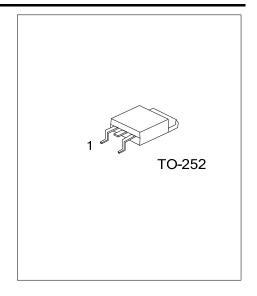


■ ORDERING INFORMATION

Ordering Number		Dookogo	Pin Assignment			Dooking	
Lead Free Halogen Free		Package	1	2	3	Packing	
UTT18P06L-TN3-R	UTT18P06G-TN3-R	TO-252	G	D	S	Tape Reel	
UTT18P06L-TN3-T	UTT18P06G-TN3-T	TO-252	G	D	S	Tube	

Note: Pin Assignment: G: Gate D: Drain S: Source





■ **ABSOLUTE MAXIMUM RATINGS** (T_A=25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT	
Drain-Source Voltage		V_{DSS}	-60	V	
Gate-Source Voltage		V_{GSS}	±20	V	
Drain Current	Continuous	T _C =25°C	I_{D}	-18.3	Α
	Pulsed		I_{DM}	-73.2	Α
Single Pulsed Avalanche Current (L=0.1mH)		I _{AS}	-18.3	Α	
Single Pulsed Avalanche Energy (L=0.1mH) (Note 1)		E _{AS}	24.2	mJ	
Power Dissipation (Note 2)		J	38.5	W	
		P _D	2.3	W	
Junction Temperature		T_J	+150	°C	
Storage Temperature		T_{STG}	-55~+150	°C	

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL DATA

PARAMETER		SYMBOL	RATINGS	UNIT
Junction to Ambient	Steady state	θ_{JA}	55	°C/W
Junction to Case		θ_{JC}	3.25	°C/W

Notes: 1. Duty cycle≤1 %.

2. See SOA curve for voltage derating.

■ ELECTRICAL CHARACTERISTICS (T_J=25°C, unless otherwise specified)

PARAMETER		SYMBOL	TEST CONDITIONS		TYP	MAX	UNIT
OFF CHARACTERISTICS							
Drain-Source Breakdown Voltage		BV _{DSS}	I _D =-250μA, V _{GS} =0V	-60			V
Drain-Source Leakage Current		I _{DSS}	V _{DS} =-60V, V _{GS} =0V			-1	μΑ
Cata Sauraa Laakaga Current	Forward	I _{GSS}	V _{GS} =+20V, V _{DS} =0V			+100	nΑ
Gate-Source Leakage Current	Reverse		V _{GS} =-20V, V _{DS} =0V			-100	nA
ON CHARACTERISTICS							
Gate Threshold Voltage		$V_{GS(TH)}$	$V_{DS}=V_{GS}$, $I_D=-250\mu A$	-1		-3	V
Static Drain-Source On-State Resistance		R _{DS(ON)}	V _{GS} =-10V, I _D =-18.3A (Note 1)		0.048	0.060	Ω
On State Drain Current (Note 1)		I _{D(ON)}	V _{GS} =-10V, V _{DS} =-5V	-30			Α
DYNAMIC PARAMETERS (Note 2)							
Input Capacitance		C _{ISS}	\\ 0\\ \\ 0\\ \\ 0\\ \\ 0\\ \\ \\ \\ 0\\ \\		1140	1710	pF
Output Capacitance		Coss	V _{GS} =0V, V _{DS} =-25V, f=1.0MHz		130		pF
Reverse Transfer Capacitance		C _{RSS}	(Note 2)		90		pF

■ ELECTRICAL CHARACTERISTICS(Cont.)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT			
SWITCHING PARAMETERS									
Total Gate Charge	Q_{G}	1/ - 10// 1/ - 20//		26	40	nC			
Gate to Source Charge	Q_GS	V _{GS} =-10V, V _{DS} =-30V, I _D =-18.3A (Note 3)		4.5		nC			
Gate to Drain Charge	Q_GD	ID=-18.5A (Note 3)		7.0		nC			
Turn-ON Delay Time	t _{D(ON)}			40		ns			
Rise Time	t _R	V_{DD} =-30V, I_{D} =-1A, R_{G} =2.5 Ω		58		ns			
Turn-OFF Delay Time	t _{D(OFF)}	(Note 3)		150		ns			
Fall-Time	t _F			60		ns			
SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS (T _C =25°C) (Note 2)									
Maximum Body-Diode Continuous Current	Is				-18.3	Α			
Maximum Body-Diode Pulsed Current	I _{SM}				-73.2	Α			
Drain-Source Diode Forward Voltage	V_{SD}	I _F =-18.3A, V _{GS} =0V (Note 1)		-1.0	-1.5	V			
Body Diode Reverse Recovery Time	t _{rr}	I _F =-18.3A, dI _F /dt=100A/μs		14	61	ns			

Notes: 1. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

- 2. Guaranteed by design, not subject to production testing.
- 3. Independent of operating temperature.

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